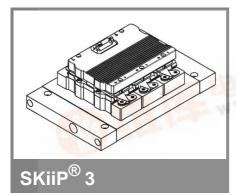
#### 捷多邦,专业PCB打样工厂,24小时加急出货

# SKiiP 1803GB172-3DW



### 2-pack-integrated intelligent Power System

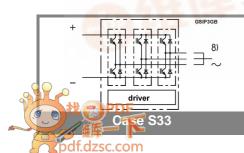
Power section

SKiiP 1803GB172-3DW

Preliminary Data

### Features

- SKiiP technology inside
- Trench IGBTs
- CAL diode technology
- Integrated current sensor
- Integrated teperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP<sup>®</sup> 3 System)
- IEC 60068-1 (climate) 40/125/56
- UL recognized file no. E63532
- with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)
- AC connection busbars must be connected by the user; copper busbars available on request

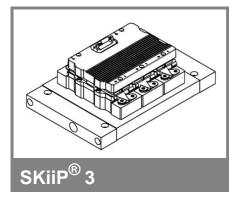


Absolute Maximum Ratings						
Symbol Conditions		Values	Units			
IGBT	17.00					
V <sub>CES</sub>	Mag	1700	V			
V <sub>CES</sub> V <sub>CC</sub> <sup>1)</sup>	Operating DC link voltage	1200	V			
V <sub>GES</sub>		± 20	V			
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1800 (1350)	Α			
Inverse diode						
I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	1400 (1050)	A			
I <sub>FSM</sub>	T <sub>j</sub> = 150 °C, t <sub>p</sub> = 10 ms; sin	10200	A			
I²t (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	520	kA²s			
T <sub>j</sub> , (T <sub>stg</sub> )		- 40 + 150 (125)	°C			
V <sub>isol</sub>	rms, AC, 1 min, m <mark>ain termin</mark> als to heat sink	4000	V			
I <sub>AC-terminal</sub>	per AC terminal, rms, T <sub>s</sub> = 70 °C,	400	А			
4-12	T <sub>terminal</sub> <115 °C					

Characteristics			$T_s = 25^{\circ}C$ unless otherwise specified					
Symbol	Conditions			min.	typ.	max.	Units	
IGBT								
V <sub>CEsat</sub>	I <sub>C</sub> = 900 A, T measured at term	j = 25 (125	) °C;		1.94	1,9 (2,2)	2,4	V
	measured at term	linai			22			
V <sub>CEO</sub>	T <sub>i</sub> = 25 (125)	°C; at tern	ninal		Sec.	1 (0,9)	1,2 (1,1)	V
r <sub>CE</sub>	$T_{i} = 25 (125)$					1 (1,4)	1,3 (1,7)	mΩ
I <sub>CES</sub>	$V_{GE} = 0 V, V_{O}$ T <sub>i</sub> = 25 (125)	<sub>CE</sub> = V <sub>CES</sub> , °C				mA		
E <sub>on</sub> + E <sub>off</sub>	I <sub>C</sub> = 900 A, V		/			mJ		
W.07	T <sub>j</sub> = 125 °C, V	V <sub>CC</sub> = 1200	V			mJ		
R <sub>CC+EE'</sub>	terminal chip	, T <sub>j</sub> = 25 °C	)			0,17		mΩ
L <sub>CE</sub>	top, bottom					4		nH
C <sub>CHC</sub>	per phase, A	C-side				3	126	nF
Inverse o	diode				1.00	- 77	1320	M
$V_F = V_{EC}$	I <sub>F</sub> = 900 A, T <sub>j</sub> measured at term	= 25 (125	) °C		E E	2 (1,8)	2,15	V
	measured at term	linal			See.			
V <sub>TO</sub>	T <sub>i</sub> = 25 (125)	°C			-	1,1 (0,8)	1,2 (0,9)	V
r <sub>T</sub>	$T_{i} = 25 (125)$					1 (1,1)	1,1 (1,2)	mΩ
Err	I <sub>C</sub> = 900 A, V	<sub>CC</sub> = 900 \	1			108		mJ
7	T <sub>j</sub> = 125 °C, V <sub>CC</sub> = 1200 V				mJ			
Mechani	cal data							
M <sub>dc</sub>	DC terminals				6		8	Nm
$M_{ac}$	AC terminals				13		15	Nm
w	SKiiP <sup>®</sup> 3 System w/o heat sink				2,4		kg	
w	heat sink					5,2	0.00	kg
	characteris							
	reference 1	to built-	in tem	perature	sensor	(acc.IEC	0.017	) K/W
R <sub>th(j-s)I</sub>							,	
R <sub>th(j-s)D</sub>	per diode						0,033	K/W
Z <sub>th</sub>	R <sub>i</sub> (mK/W) (m 1	ax. values	s) 3	4	1	tau 2	i(s) 3	4
7.02	1,4	2 6,8	3 7,8	4	69	2 0,35	0,02	4 1
Z <sub>th(j-r)I</sub> Z <sub>th(j-r)D</sub>	2,6	4	17,7	17,7	50	5	0,02	0,04
Z <sub>th(r-a)</sub>	4,6	4,7	1,1	0,6	48	15	2,8	0,4
un(r-a)			,	- , -	-	-	, -	- ,

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# SKiiP 1803GB172-3DW



## 2-pack-integrated intelligent Power System

2-pack integrated gate driver SKiiP 1803GB172-3DW

Preliminary Data

#### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 60068-1 (climate) 40/85/56
- UL recognized file no. 242581

Absolute	e Maximum Ratings	$a = 25^{\circ}$ C unless otherwise specified		
Symbol	Conditions	Values	Units	
V <sub>S2</sub>	unstabilized 24 V power supply	30	V	
V <sub>i</sub>	input signal voltage (high)	15 + 0,3	V	
dv/dt	secondary to primary side	75	kV/μs	
V <sub>isollO</sub>	input / output (AC, rms, 2s)	4000	V	
VisoIPD	partial discharge extinction voltage, rms, $Q_{PD} \leq 10 \text{ pC}$ ;	1500	V	
V <sub>isol12</sub>	output 1 / output 2 (AC, rms, 2s)	1500	V	
f <sub>sw</sub>	switching frequency	9	kHz	
f <sub>out</sub>	output frequency for I=I <sub>C</sub> ; sin.	1	kHz	
T <sub>op</sub> (T <sub>stg</sub> )	operating / storage temperature	- 40 + 85	°C	

Characte	ristics	(T <sub>a</sub> :			= 25°C)
Symbol	Conditions	min.	typ.	max.	Units
V <sub>S2</sub>	supply voltage non stabilized	13	24	30	V
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	380+34*f/kHz+0,00015*(I <sub>AC</sub> /A) <sup>2</sup>			mA
V <sub>iT+</sub>	input threshold voltage (High)			12,3	V
V <sub>iT-</sub>	input threshold voltage (Low)	4,6			V
R <sub>IN</sub>	input resistance		10		kΩ
CIN	input capacitance		1		nF
t <sub>d(on)IO</sub> t <sub>d(off)IO</sub>	input-output turn-on propagation time input-output turn-off propagation time		1,3 1,3		μs µs
t <sub>pERRRESET</sub>	error memory reset time		9		μs
t <sub>TD</sub>	top / bottom switch interlock time		3,3		μs
l analogOUT	max. 5mA; 8 V corresponds to 15 V supply voltage for external components		1500		A
I <sub>s1out</sub>	max. load current			50	mA
I <sub>TRIPSC</sub> T <sub>tp</sub> U <sub>DCTRIP</sub>	over current trip level (I <sub>analog</sub> OUT = 10 V) over temperature protection U <sub>DC</sub> -protection ( U <sub>analog OUT</sub> = 9 V);	110	1875 not	120	A ℃ V
- DCTRIP	(option for GB types)	i	mplemented	d	-

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